# **Literature Study**

# Electron energy-loss spectroscopy in the Transmission Electron Microscope (TEM)

https://s3-us-west-2.amazonaws.com/secure.notion-static.com/207414 95-585d-46c6-89a8-b04738b50820/2008\_Egerton-RepProgPhys72.pd f

# Information in the paper includes:

# 1. The workings of an TEM

The transmission electron microscope works by accelerating electrons and shooting them through a material, this results in electrons with different velocities which will be separated into a spectrum by a magnetic prism. This spectrum then falls upon a detector.

# 2. The physics of an Electron Energy-Loss Spectrum

The aforementioned spectrum is a superimposed spectrum of smaller spectrums which are the result of different interactions between the sample and the shot electrons.

The paper continuously talks about a "differential cross section" expressed by  $\sigma$  which is a measure of probability for scattering to occur.

# **Elastic Scattering**

This type of scattering transforms energy from the shot electron to the sample, its angular distribution is quite narrow. The scattering angle is a result of how close the shot electron passes the nucleus of an atom. These angles are discretised and called Bragg angles, (I assume this relates quite closely to the studied material for Solid State Physics were this was due to the repeating lattice). The scattering angles can be widened due to extra phonon scattering but these energies are to low to be measured in a TEM-EELS system. Probability is given by  $d\sigma/d\Omega$  where  $\Omega$  is the absolute angle.

# **Inelastic Scattering**

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Coulomb interaction gives rise to this type of scattering. Due to the similarity in mass (probably talking about effective masses  $m^*$ ) between the projectile (shot electron) and target (electron bound to sample) the energy loss of the shot electron is quite large,  $1...10^2 eV$ . Probability is given by  $d^2\sigma/d\Omega dE$ .

#### **Plasmon excitation**

A phenomenon that arises because outer-shell electrons are weakly bound to the atoms but enjoy a strong interaction by electrostatic forces and thus form an energy band. When a high energy electron travels trough a material at a speed higher then the Fermi-speed in that material the electron pushes away the surrounding electrons which leaves a relatively positive wake behind, this creates a net force decelerating the speeding electron. *Interesting*.

The energy loss is a result of plasmon-loss event which are related to the mean free path of an electron. This quantity can be used to estimate the thickness of the material (Here).

# **Surface plasmons and radiation loss**

Before the electrons even reach the specimen they polarise its entire surface, in case of a conducting sample longitudinal charge-density waves can be observed. The frequency of these waves is a direct result from the permittivity of the sample thus knowing the loss in energy of an electron due to this effect yields information about the sample permittivity.

#### Single-electron excitation and fine structure

In addition to the previously stated effect a incident shot electron can also excite a single electron into a higher energy state, these can be observed by fine-structure peaks that occur at energies above and below the plasmon peak, resulting in a more jagged profile. Between the 0-10eV range.

#### **Core-electron excitation**

Electrons located in the inner shells of a atom have high binding energies (  $10^2...10^3 eV$ ) whose ionisation gives rise to the **ionisation edges** in the ELS. Since these edges are different for every atom they can be used to determine which materials are present in a sample.

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#### **Core-Loss fine structure**

Depends on the density of states

# 3. Applications and Limitations of TEM-EELS

#### Thickness measurement

The spectrum can be used to provide a per pixel thickness of the material

# **Electron properties**

The spectrum can provide information of the bandgap of semiconductors and insulator.

### Plasmon spectroscopy

The plasmon energy is related to many mechanical properties of the material

# **Elemental analysis**

Because each ionisation edge occurs at an energy loss that is characteristic of a particular element, EELS can identify elements in a material.

# **Spatial resolution**

EELS provides a spatial resolution of about 0.2nm when compensating for aberrations, to go beyond this point room sized specialised set-up are needed

#### **Magnetic measurments**

Using a spin-polarised electron source the local magnetic properties of a material can be mapped.

#### **Damage**

Shooting electrons at a sample damages it with doses needed for a certain degree of damage differing per material. Resembles the radiation dose calculations from HS.

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